## NSN 5961-00-494-3351

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View Online at https://aerobasegroup.com/nsn/5961-00-494-3351 **Inclosure Material:** Metal all transistor **Overall Length:** 1.573 inches all transistor **Overall Height:** 0.350 inches **Overall Width:** 1.050 inches all transistor **Mounting Facility Quantity:** 2 all transistor **Internal Configuration:** Junction contact all transistor Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-3 all transistor **Electrode Internally-electrically Connected To Case:** Collector all transistor **Internal Junction Configuration:** Npn all transistor **Component Function Relationship:** Matched **Component Name And Quantity:** 2 transistor **Mounting Method:** Unthreaded hole all transistor **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon all transistor Voltage Rating In Volts Per Characteristic: 140.0 breakdown voltage, collector-to-emitter, base open all transistor **Current Rating Per Characteristic:** 16.00 amperes source cutoff current all transistor **Power Rating Per Characteristic:** 150.0 watts small-signal input power, common-collector absolute all transistor **Maximum Operating Tempurature Per Measurement Point:** 175.0 degrees celsius junction all transistor **Terminal Type And Quantity:** 2 pin all transistor and 1 case all transistor Shelf Life:

N/a

**Unit Of Measure:** 

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Demilitarization:

No

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